

KFL-1ML-N

1. Description

The KFL-1ML-N is a high-power GaAlAs IRED mounted in TO-46K type header with clear epoxy encapsulation. The IRED have a with angular response and relatively low-cost compared to can type devices.

2. Features

Wide angular response

Peak emission wavelength ?p=850nm

Relativery low-cost againstmetal can package

Low profile package

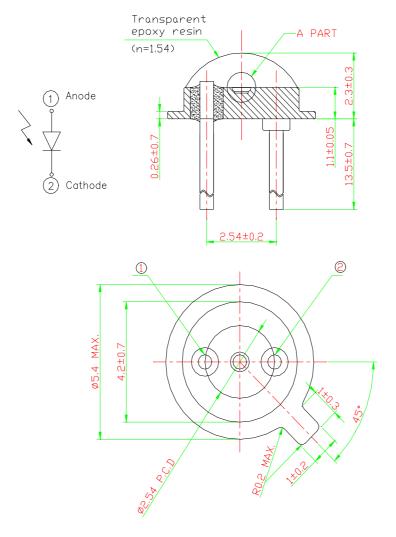
3. Applications

Transportation sensors

Security switches

4. Package Outline

ALL DIMENSIONS IN MILLIMETERS



Infrared Emitting Diodes(GaAlAs)



KFL-1ML-N

5. Absolute Maximum Ratings

 $[T_A = 25]$

Parameter	Symbol	Ratings	Unit
Reverse Voltage	V_R	5	V
Forward Current	I _F	80	mA
Pulse Forward Current (see Note 1)	I _{FP}	1	А
Power Dissipation	P_D	140	mW
Operating Temperature	Topr.	-25 ~ +80	
Storage Temperature	Tstg.	-30 ~ +100	
Soldering Temperature (see Note 2)	Tsol.	260	

Notes: 1. Pulse Width: tw=100 µsec. Period: T=10 msec.

6. Electro-optical Characteristics

 $[T_A = 25]$

Item	Symbol	Conditions	Min	Тур	Max	Unit
Forward Voltage	V _F	$I_F = 50 \text{ mA}$		1.5	1.7	V
Reverse Current	I _R	V _R = 5 V			10	μΑ
Capacitance	Ct	f=1MHz		25		pF
Peak Emission Wavelength	р	$I_F = 50 \text{ mA}$		850		nm
Spectral Bandwidth		$I_F = 50 \text{ mA}$		30		nm
Radiant Intensity	Po	$I_F = 50 \text{ mA}$		14		mW
Half Angle				±63		deg.

7. Inspection Criteria

7-1. In electrical and optical characteristics, all products are inspected for following 3 items.

Reverse Voltage : BV_R Forward Voltage : V_F Radiant Intensity : P_O

7-2. No particular inspections shall be carried out for items other than those above. However they shall satisfy the ratings.

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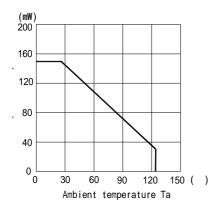
^{2.} For MAX. 5 seconds at the position of 2 mm from the resin edge.

Infrared Emitting Diodes(GaAlAs)

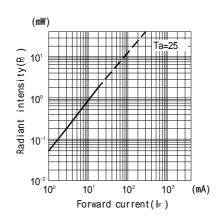
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8. Typical Electrical-optical Characteristics Curves

Power dissipation Vs. **Ambient temperature**

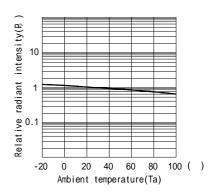


Radiant intensity Vs. **Forward current**

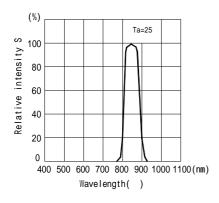


Relative radiant intensity Vs. **Ambient temperature**

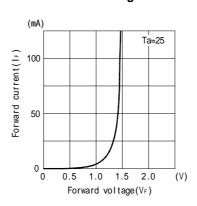
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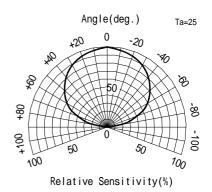
Relative intensity Vs. Wavelength



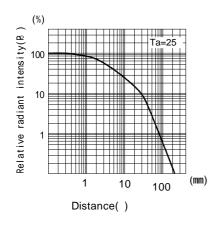
Forward current Vs. Forward voltage



Radiant Pattern



Relative radiant intensity Vs. **Distance**



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9. Cautions in Usage

- 9-1. Store and use where there is no exterior force that will cause change in shape.
- 9-2. Store and use where there is no Hydrogen Sulfide gas, or any other corrosive gas.
- 9-3. The bending or cutting of the lead should be done at room temperature, no force being applied on the package.
- 9-4. Solder the lead pin under conditions of the absolute maximum rating chart, and do not apply force on the lead pin after soldering.

10. Guarantee Period and Scope

10-1. Period

One year after delivery to the desired place.

10-2. Scope

Replacement of products will be done, if any problems lie in our company's products.

However, we are not liable for your damage by lack of caution.

11. Others

Any doubts concerning this specfication should be discussed fully by both parties.

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